TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCX16601FT

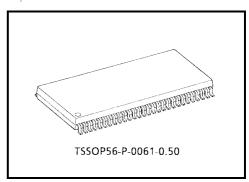
Low-Voltage 18-Bit Universal Bus Transceiver with 3.6-V Tolerant Inputs and Outputs

The TC74VCX16601FT is a high performance CMOS 18-bit universal bus transceiver. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs up to $3.6\ V.$

 \overline{Data} flow in each direction is controlled by output-enable (\overline{OEAB} and \overline{OEBA}), latch-enable (LEAB and LEBA), and clock (CKAB and CKBA) inputs. The clock can be controlled by the clock-enable (CKENAB and CKENBA) inputs.

For A-to-B data flow, the device operates in the transparent mode when LEAB is high. When LEAB is low, the A data is latched if CKAB is held at a high or low logic level. If LEAB is low,



Weight: 0.25 g (typ.)

the A-bus data is stored in the latch/flip-flop on the low-to-high transition of CKAB.

Data flow for B to A is similar to that of A to B but uses OEBA, LEBA, CKBA, and CKENBA.

When the OE input is high, the outputs are in a high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.

Features

- Low-voltage operation: VCC = 1.8 to 3.6 V
- High-speed operation: $t_{pd} = 2.9 \text{ ns (max) (VCC} = 3.0 \text{ to } 3.6 \text{ V)}$

 $t_{pd} = 3.5 \text{ ns (max) (VCC} = 2.3 \text{ to } 2.7 \text{ V)}$

 $: t_{pd} = 7.0 \text{ ns (max) (VCC} = 1.8 \text{ V)}$

• Output current: $IOH/IOL = \pm 24 \text{ mA (min)} (VCC = 3.0 \text{ V})$

 $: I_{OH}/I_{OL} = \pm 18 \text{ mA (min) (V}_{CC} = 2.3 \text{ V)}$

: $I_{OH}/I_{OL} = \pm 6 \text{ mA (min) (V}_{CC} = 1.8 \text{ V)}$

- Latch-up performance: ±300 mA
- ESD performance: Machine model > ±200 V

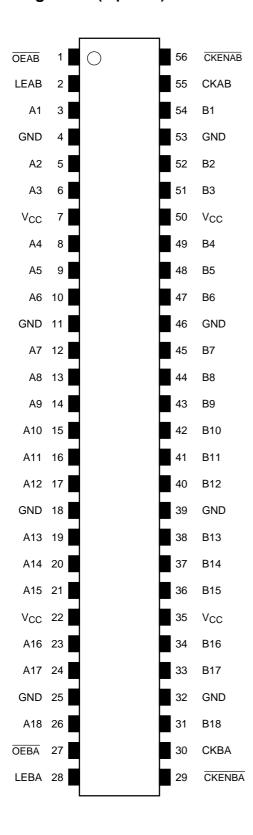
: Human body model $> \pm 2000 \text{ V}$

- Package: TSSOP (thin shrink small outline package)
- Bidirectional interface between 2.5 V and 3.3 V signals.
- 3.6-V tolerant function and power down-protection provided on all inputs and outputs

Note: Do not apply a signal to any bus pins when it is in the output mode. Damage may result.

All floating (high impedance) bus pins must have their input level fixed by means of pull-up or pull-down resistors.

Pin Assignment (top view)



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Truth Table (A bus → B bus)

	Outputs				
CKENAB	OEAB	LEAB	CKAB	Α	В
Х	Н	Х	Х	Х	Z
Х	L	Н	Х	L	L
Х	L	Н	Х	Н	Н
Н	L	L	Х	Х	В0
П	L	L	^	^	(Note 2)
Н	L	L	Х	Х	В0
11	L	L	^	^	(Note 2)
L	لـ	لـ	4	لــ	L
L	لـ	لـ	4	H	Н
L	L	L	L	Х	В0
	L	L	L	^	(Note 1)
L	L	L	Н	Х	В0
L	L	L	11	^	(Note 1)

Note 1: Output level before the indicated steady-state input conditions were established, provided that CKAB was low or high before LEAB went low.

Note 2: Output level before the indicated steady-state input conditions were established, provided that $\overline{\mathsf{CKENAB}}$ was low or high before LEAB went low.

Truth Table (B bus → A bus)

	Inputs							
CKENBA	OEBA	LEBA	CKBA	В	А			
Х	Н	Х	Х	Х	Z			
Х	L	Н	Х	L	L			
Х	L	Н	Х	Н	Н			
Н	L	L	Х	X	A0			
П	L	L	^	^	(Note 4)			
Н	L	L	X	X	A0			
- 11	<u> </u>	<u> </u>	^	^	(Note 4)			
L	L	L		L	L			
L	L	L		Н	Н			
L	L	L	L	X	A0			
L	L	L	L	^	(Note 3)			
L	L	L	Н	X	A0			
	L	L	17	^	(Note 3)			

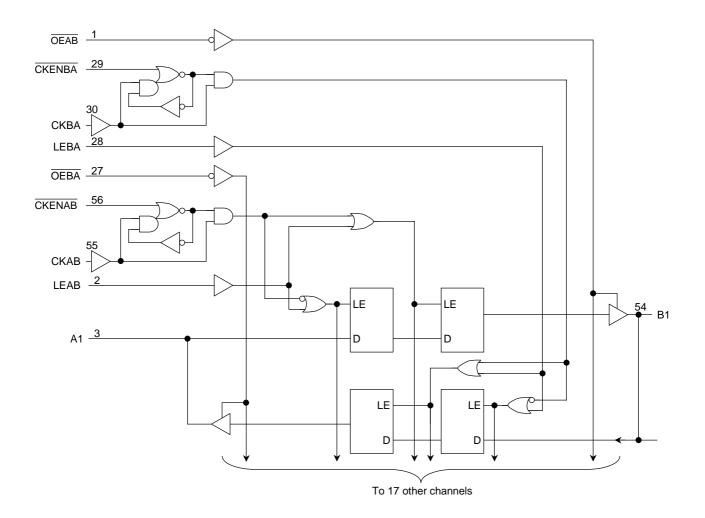
Note 3: Output level before the indicated steady-state input conditions were established, provided that CKBA was low or high before LEBA went low.

Note 4: Output level before the indicated steady-state input conditions were established, provided that

CKENBA was low or high before LEBA went low.

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System Diagram



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Maximum Ratings

Characteristics	Symbol	Rating	Unit
Power supply voltage	Vcc	-0.5 to 4.6	V
DC input voltage (OEAB, OEBA, LEAB, LEBA, CKAB, CKBA, CKENAB, CKENBA)	V _{IN}	-0.5 to 4.6	V
DC bus I/O voltage	V _{I/O}	-0.5 to 4.6 (Note 5) -0.5 to V _{CC} + 0.5 (Note 6)	V
Input diode current	I _{IK}	-50	mA
Output diode current	I _{OK}	±50 (Note 7)	mA
DC output current	lout	±50	mA
Power dissipation	P _D	400	mW
DC V _{CC} /ground current per supply pin	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65 to 150	°C

Note 5: OFF state

Note 6: High or low state. $I_{\mbox{OUT}}$ absolute maximum rating must be observed.

Note 7: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Recommended Operating Range

Characteristics	Symbol Rating		Unit	
Power supply voltage	V	1.8 to 3.6	V	
Fower supply voltage	V _{CC}	1.2 to 3.6 (Note 8)	V	
Input voltage (OEAB , OEBA , LEAB , LEBA , CKAB , CKBA , CKENAB , CKENBA)	V _{IN}	-0.3 to 3.6	V	
Bus I/O voltage	Viva	0 to 3.6 (Note 9)	V	
Bus I/O voitage	V _{I/O}	0 to V _{CC} (Note 10)	V	
		±24 (Note 11)		
Output current	I _{OH} /I _{OL}	±18 (Note 12)	mA	
		±6 (Note 13)		
Operating temperature	T _{opr}	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 14)	ns/V	

Note 8: Data retention only

Note 9: OFF state

Note 10: High or low state

Note 11: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 12: $V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$

Note 13: $V_{CC} = 1.8 \text{ V}$

Note 14: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V



Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C, 2.7 V < V_{CC} \leq 3.6 V)

Characte	ristics	Symbol	Test	Condition	V _{CC} (V)	Min	Max	Unit						
	H-level	VIH		_	2.7 to 3.6	2.0	_							
Input voltage	L-level	V _{IL}		_	2.7 to 3.6	_	0.8	V						
				I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2	_							
	H-level	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -12 \text{ mA}$	2.7	2.2	_							
				I _{OH} = -18 mA	3.0	2.4	_							
Output voltage				I _{OH} = -24 mA	3.0	2.2	_	V						
,			V_{OL} $V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 100 \mu A$	2.7 to 3.6	_	0.2							
	L-level	Mari		$V_{IN} = V_{IH} \text{ or } V_{IL}$	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 12 mA	2.7	_	0.4				
	L-ievei	VOL					AIN — AIH OI AIL	AIN — AIH OI AIL	AIN — AIH OL AIL	VIN - VIH OI VIL	AIN — AIH OI AIL	AIN — AIH OI AIL	AIN — AIH OI AIL	I _{OL} = 18 mA
				I _{OL} = 24 mA	3.0	_	0.55							
Input leakage curre	ent	I _{IN}	V _{IN} = 0 to 3.6 V	·	2.7 to 3.6	_	±5.0	μА						
3-state output OFF	E state current	la-	$V_{IN} = V_{IH}$ or V_{IL}		2.7 to 3.6		±10.0	μА						
3-state output OFF	State Current	l _{OZ}	V _{OUT} = 0 to 3.6 V		2.7 10 3.6		±10.0	μΑ						
Power-off leakage	current	I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0		10.0	μΑ						
Quiescent supply current		loo	V _{IN} = V _{CC} or GND		2.7 to 3.6		20.0							
Quiescerit supply (Curcil	Icc	$V_{CC} \le (V_{IN}, V_{OUT}) \le 3.6 \text{ V}$		2.7 to 3.6		±20.0	μΑ						
Increase in I _{CC} pe	r input	Δl _{CC}	V _{IH} = V _{CC} - 0.6 V		2.7 to 3.6	_	750							

DC Characteristics (Ta = -40 to 85°C, 2.3 V \leq V_{CC} \leq 2.7 V)

Characte	ristics	Symbol	Test	Condition	V _{CC} (V)	Min	Max	Unit				
Innut voltage	H-level	V _{IH}		_	2.3 to 2.7	1.6	_	V				
Input voltage	L-level	V _{IL}		_	2.3 to 2.7	_	0.7	V				
				I _{OH} = -100 μA	2.3 to 2.7	V _{CC} - 0.2	_					
	H-level	Voн	V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -6 \text{ mA}$	2.3	2.0	_					
							I _{OH} = -12 mA	2.3	1.8	_		
Output voltage				I _{OH} = -18 mA	2.3	1.7	_	V				
								$I_{OL} = 100 \mu A$	2.3 to 2.7	_	0.2	
	L-level	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 12 mA	2.3	_	0.4					
				I _{OL} = 18 mA	2.3	_	0.6					
Input leakage curre	ent	I _{IN}	V _{IN} = 0 to 3.6 V		2.3 to 2.7	_	±5.0	μΑ				
2 state suitaut OFF	- ototo ourront	1	V _{IN} = V _{IH} or V _{IL}		2.3 to 2.7		±10.0					
3-state output OFF state current		loz	V _{OUT} = 0 to 3.6 V	V _{OUT} = 0 to 3.6 V			±10.0	μΑ				
Power-off leakage	current	I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0	_	10.0	μА				
Quioscont supply	current	loo	V _{IN} = V _{CC} or GND		2.3 to 2.7	_	20.0					
Quiescent supply of	- Curretti	Icc	$V_{CC} \le (V_{IN}, V_{OUT}) \le 1$	3.6 V	2.3 to 2.7	_	±20.0	μΑ				



DC Characteristics (Ta = -40 to 85°C, 1.8 V \leq V_{CC} < 2.3 V)

Characteristics		Symbol	Test Co	ondition		Min	Max	Unit
		Í						
Input voltage	H-level	V_{IH}	_	_	1.8 to 2.3	$^{0.7\times}_{\text{VCC}}$		V
input voltage	L-level	V_{IL}	-	_	1.8 to 2.3		0.2 × V _{CC}	v
	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	1.8	V _{CC} - 0.2		
Output voltage				I _{OH} = -6 mA	1.8	1.4	_	V
	L-level	Vol	VIN = VIH or VII	I _{OL} = 100 μA	1.8	_	0.2	
	L-level	VOL	VIN - VIH OI VIL	I _{OL} = 6 mA	1.8	_	0.3	
Input leakage currer	nt	I _{IN}	$V_{IN} = 0$ to 3.6 V		1.8	_	±5.0	μΑ
3-state output OFF s	state current	l _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$			_	±10.0	μА
Power-off leakage c	urrent	I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0	_	10.0	μΑ
Quiescent supply cu	ırrent	laa	$V_{IN} = V_{CC}$ or GND		1.8		20.0	μА
Quiescent supply ed	III CIII	Icc	$V_{CC} \le (V_{IN}, V_{OUT}) \le 3.6$	3 V	1.8	_	±20.0	μΛ

AC Characteristics (Ta = -40 to 85°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF, $R_L = 500$ Ω)

Characteristics	Symbol	Test Condition		Min	Max	Unit
			V _{CC} (V)			
			1.8	100	_	
Maximum clock frequency	f _{max}	Figure 1, Figure 3	2.5 ± 0.2	200	_	MHz
			3.3 ± 0.3	250	_	
Propagation delay time	t _{pLH}		1.8	1.5	7.0	
(An, Bn-Bn, An)	t _{pHL}	Figure 1, Figure 2	2.5 ± 0.2	1.0	3.5	ns
, , , ,	PINE		3.3 ± 0.3	0.8	2.9	
Propagation delay time	t _{pLH}		1.8	1.5	8.8	
(CKAB, CKBA-Bn, An)	t _{pHL}	Figure 1, Figure 3	2.5 ± 0.2	1.0	4.4	ns
(Oroxis, Oroxis Bri, 7th)	ФПС		3.3 ± 0.3	0.8	3.5	
Propagation delay time	•		1.8	1.5	8.8	
(LEAB, LEBA-Bn, An)	t _{pLH}	Figure 1, Figure 4	2.5 ± 0.2	1.0	4.4	ns
(LEAD, LEDA-DII, AII)	t _{pHL}		3.3 ± 0.3	0.8	3.5	
0	,	Figure 1, Figure 6	1.8	1.5	9.8	
Output enable time	t _{pZL}		2.5 ± 0.2	1.0	4.9	ns
(OEAB, OEBA-Bn, An)			3.3 ± 0.3	0.8	3.8	
			1.8	1.5	7.6	ns
Output disable time	t _{pLZ}	Figure 1, Figure 6	2.5 ± 0.2	1.0	4.2	
(OEAB, OEBA-Bn, An)	t _{pHZ}		3.3 ± 0.3	0.8	3.7	
			1.8	4.0	_	
Minimum pulse width	tW (H)	Figure 1, Figure 3, Figure 4	2.5 ± 0.2	1.5	_	ns
	t _{W (L)}		3.3 ± 0.3	1.5	_	
			1.8	2.5	_	
Minimum set-up time	t _s	Figure 1, Figure 3, Figure 4, Figure 5	2.5 ± 0.2	1.5	_	ns
			3.3 ± 0.3	1.5	_	
			1.8	1.0	_	
Minimum hold time	th	Figure 1, Figure 3, Figure 4, Figure 5	2.5 ± 0.2	1.0		ns
	"		3.3 ± 0.3	1.0	_	
			1.8		0.5	
Output to output skew	t _{osLH}	(Note 15)	2.5 ± 0.2		0.5	ns
	t _{osHL}	(.10.0 10)	3.3 ± 0.2		0.5	
			J.J _ U.J		0.5	

For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 15: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$



Dynamic Switching Characteristics

(Ta = 25°C, input: $t_r = t_f = 2.0 \text{ ns}$, $C_L = 30 \text{ pF}$, $R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Тур.	Unit
		V _{IH} = 1.8 V, V _{IL} = 0 V	(Note 16)	1.8	0.25	
Quiet output maximum dynamic V _{OL}	V_{OLP}	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$	(Note 16)	2.5	0.6	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note 16)	3.3	0.8	
		V _{IH} = 1.8 V, V _{IL} = 0 V	(Note 16)	1.8	-0.25	
Quiet output minimum dynamic V _{OL}	V_{OLV}	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$	(Note 16)	2.5	-0.6	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note 16)	3.3	-0.8	
		V _{IH} = 1.8 V, V _{IL} = 0 V	(Note 16)	1.8	1.5	
Quiet output minimum dynamic V _{OH}	V_{OHV}	V _{IH} = 2.5 V, V _{IL} = 0 V	(Note 16)	2.5	1.9	V
		V _{IH} = 3.3 V, V _{IL} = 0 V	(Note 16)	3.3	2.2	

Note 16: Parameter guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	_		1.8, 2.5, 3.3	6	pF
Bus I/O capacitance	C _{I/O}	_		1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C _{PD}	$f_{IN} = 10 \text{ MHz}$ (N	lote 17)	1.8, 2.5, 3.3	20	pF

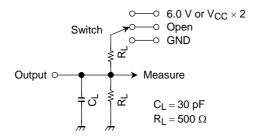
Note 17: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/18 \text{ (per bit)}$

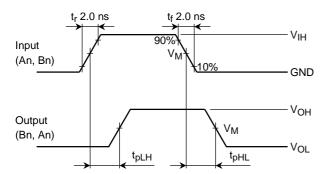
AC Test Circuit



Parameter	Switch		
t _{pLH} , t _{pHL}	Open		
t _{pLZ} , t _{pZL}	$ \begin{array}{cccccccccccccccccccccccccccccccccccc$		
t _{pHZ} , t _{pZH}	GND		

Figure 1

AC Waveform



Symbol	Vcc							
Symbol	$3.3\pm0.3~\textrm{V}$	$2.5\pm0.2\textrm{V}$	1.8 V					
V _{IH}	2.7 V	V _{CC}	Vcc					
V _M	1.5 V	V _{CC} /2	V _{CC} /2					
VX	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V					
VY	V _{OH} – 0.3 V	V _{OH} – 0.15 V	V _{OH} – 0.15 V					

Figure 2 t_{pLH} , t_{pHL}

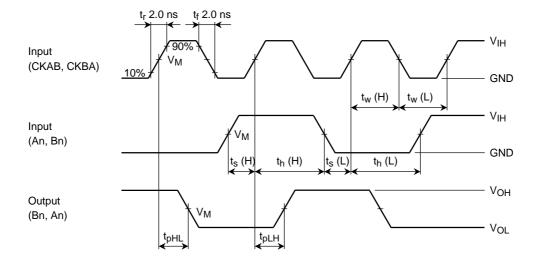


Figure 3 $t_{pLH}, t_{pHL}, t_w, t_s, t_h$

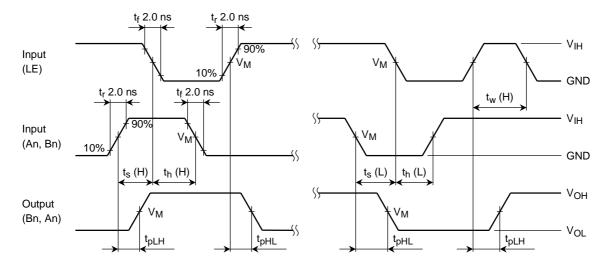


Figure 4 t_{pLH}, t_{pHL}, t_w, t_s, t_h

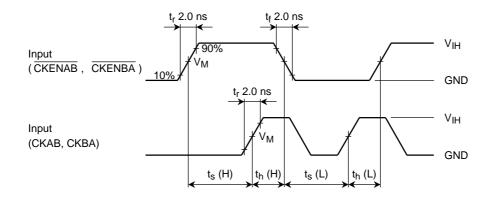
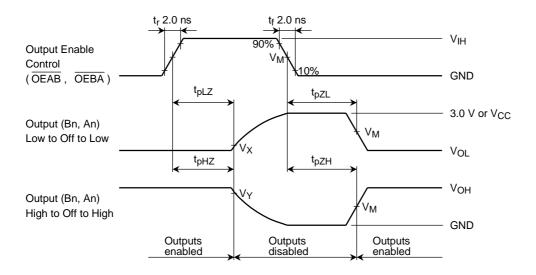


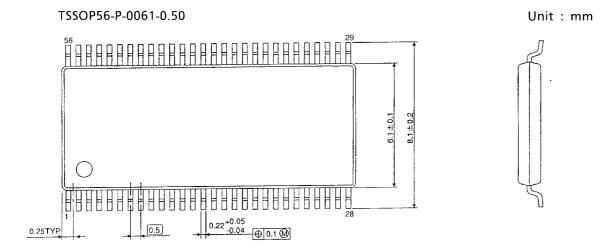
Figure 5 t_s, t_h

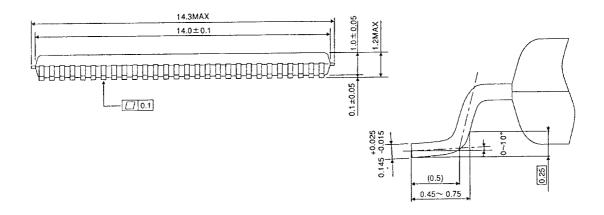


 $\textbf{Figure 6} \quad t_{\text{pLZ}},\, t_{\text{pHZ}},\, t_{\text{pZL}},\, t_{\text{pZH}}$

Package Dimensions

TOSHIBA





Weight: 0.25 g (typ.)

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